

# 74HC244; 74HCT244

Octal buffer/line driver; 3-state

Product data sheet

## 1. General description

The 74HC244; 74HCT244 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL).

The 74HC244; 74HCT244 has octal non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs  $1\overline{OE}$  and  $2\overline{OE}$ . A HIGH on  $n\overline{OE}$  causes the outputs to assume a high-impedance OFF-state. The 74HC244; 74HCT244 is identical to the 74HC240; 74HCT240 but has non-inverting outputs.

## 2. Features

- Octal bus interface
- Non-inverting 3-state outputs
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-C exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$

## 3. Quick reference data

Table 1: Quick reference data

$GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f = 6\text{ ns}$

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>74HC244</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	$V_{CC} = 5\text{ V}$ ; $C_L = 15\text{ pF}$	-	9	-	ns
$C_i$	input capacitance		-	3.5	-	pF
$C_{PD}$	power dissipation capacitance	per buffer; $V_I = GND$ to $V_{CC}$	[1]	-	35	pF
<b>74HCT244</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	$V_{CC} = 5\text{ V}$ ; $C_L = 15\text{ pF}$	-	11	-	ns
$C_i$	input capacitance		-	3.5	-	pF
$C_{PD}$	power dissipation capacitance	per buffer; $V_I = GND$ to ( $V_{CC} - 1.5\text{ V}$ )	[1]	-	35	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

**PHILIPS**

$f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  
 $V_{CC}$  = supply voltage in V;  
 $N$  = number of inputs switching;  
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 4. Ordering information

Table 2: Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
<b>74HC244</b>				
74HC244N	−40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HC244D	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HC244DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HC244PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HC244BQ	−40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1
<b>74HCT244</b>				
74HCT244N	−40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HCT244D	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HCT244DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HCT244PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HCT244BQ	−40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

Table 3: Pin description ...continued

Symbol	Pin	Description
2A1	15	2 data input 1
1Y1	16	1 bus output 1
2A0	17	2 data input 0
1Y0	18	1 bus output 0
$\overline{2OE}$	19	2 output enable input (active LOW)
$V_{CC}$	20	supply voltage

## 7. Functional description

### 7.1 Function table

Table 4: Function table [1]

Control	Input	Output
$n\overline{OE}$	nAn	nYn
L	L	L
	H	H
H	X	Z

- [1] H = HIGH voltage level;  
 L = LOW voltage level;  
 X = don't care;  
 Z = high-impedance OFF-state.

## 8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
$I_{IK}$	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_{OK}$	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_O$	output current	$V_O = -0.5\text{ V}$ to $(V_{CC} + 0.5\text{ V})$	-	$\pm 35$	mA
$I_{CC}$	quiescent supply current		-	70	mA
$I_{GND}$	ground current		-	-70	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation				
	DIP20 package		[1]	-	750 mW
	SO20 package		[2]	-	500 mW
	SSOP20 package		[3]	-	500 mW
	TSSOP20 package		[3]	-	500 mW
	DHVQFN20 package		[4]	-	500 mW

- [1] For DIP20 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.  
 [2] For SO20 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.  
 [3] For SSOP20 and TSSOP20 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.  
 [4] For DHVQFN20 packages:  $P_{tot}$  derates linearly with 4.5 mW/K above 60 °C.

## 9. Recommended operating conditions

**Table 6: Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>74HC244</b>						
$V_{CC}$	supply voltage		2.0	5.0	6.0	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	25	+125	°C
$t_r, t_f$	input rise and fall time	$V_{CC} = 2.0\text{ V}$	-	-	1000	ns
		$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0\text{ V}$	-	-	400	ns
<b>74HCT244</b>						
$V_{CC}$	supply voltage		4.5	5.0	5.5	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	25	+125	°C
$t_r, t_f$	input rise and fall time	$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns

## 10. Static characteristics

**Table 7: Static characteristics 74HC244**

At recommended operating conditions; voltages are referenced to GND (ground = 0V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ °C}</math></b>						
$V_{IH}$	HIGH-state input voltage	$V_{CC} = 2.0\text{ V}$	1.5	1.2	-	V
		$V_{CC} = 4.5\text{ V}$	3.15	2.4	-	V
		$V_{CC} = 6.0\text{ V}$	4.2	3.2	-	V
$V_{IL}$	LOW-state input voltage	$V_{CC} = 2.0\text{ V}$	-	0.8	0.5	V
		$V_{CC} = 4.5\text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0\text{ V}$	-	2.8	1.8	V
$V_{OH}$	HIGH-state output voltage	$V_I = V_{IH}$ or $V_{IL}$	-	-	-	
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	1.9	2.0	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	4.4	4.5	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$	5.9	6.0	-	V
		$I_O = -6.0\text{ mA}; V_{CC} = 4.5\text{ V}$	3.98	4.32	-	V
	$I_O = -7.8\text{ mA}; V_{CC} = 6\text{ V}$	5.48	5.81	-	V	

**Table 7: Static characteristics 74HC244 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6 V	-	0.16	0.26	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6 V	-	-	±0.1	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±0.5	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	8.0	μA
C <sub>i</sub>	input capacitance		-	3.5	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6 V	5.34	-	-	V
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6 V	-	-	0.33	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±5.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	80	μA

**Table 7: Static characteristics 74HC244 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6 V	-	-	±1.0	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	-	-	±10.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	160	µA

**Table 8: Static characteristics 74HCT244**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 µA	4.4	4.5	-	V
		I <sub>O</sub> = -6.0 mA	3.98	4.32	-	V
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 µA	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.16	0.26	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	µA
I <sub>OZ</sub>	OFF-state output current	per input pin; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; other pins at GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	±0.5	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	8.0	µA

**Table 8: Static characteristics 74HCT244 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\Delta I_{CC}$	additional quiescent supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V		70	252	$\mu$ A
$C_i$	input capacitance		-	3.5	-	pF
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$V_{IH}$	HIGH-state input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	-	-	V
$V_{IL}$	LOW-state input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	-	0.8	V
$V_{OH}$	HIGH-state output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = -20$ $\mu$ A	4.4	-	-	V
		$I_O = -6.0$ mA	3.84	-	-	V
$V_{OL}$	LOW-state output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = 20$ $\mu$ A	-	-	0.1	V
		$I_O = 6.0$ mA	-	-	0.33	V
$I_{LI}$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	$\pm 1.0$	$\mu$ A
$I_{OZ}$	OFF-state output current	per input pin; $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; other pins at GND or $V_{CC}$ ; $I_O = 0$ A; $V_{CC} = 5.5$ V			$\pm 5.0$	$\mu$ A
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	$\mu$ A
$\Delta I_{CC}$	additional quiescent supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V	-	-	315	$\mu$ A
<b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b>						
$V_{IH}$	HIGH-state input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	-	-	V
$V_{IL}$	LOW-state input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	-	0.8	V
$V_{OH}$	HIGH-state output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = -20$ $\mu$ A	4.4	-	-	V
		$I_O = -6.0$ mA	3.7	-	-	V
$V_{OL}$	LOW-state output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = 20$ $\mu$ A	-	-	0.1	V
		$I_O = 6.0$ mA	-	-	0.4	V
$I_{LI}$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	$\pm 1.0$	$\mu$ A
$I_{OZ}$	OFF-state output current	per input pin; $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; other pins at GND or $V_{CC}$ ; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	$\pm 10.0$	$\mu$ A
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	$\mu$ A
$\Delta I_{CC}$	additional quiescent supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V	-	-	343	$\mu$ A

## 11. Dynamic characteristics

**Table 9: Dynamic characteristics 74HC244**
*GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 8](#).*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0$ V	-	30	110	ns
		$V_{CC} = 4.5$ V	-	11	22	ns
		$V_{CC} = 5$ V; $C_L = 15$ pF	-	9	-	ns
		$V_{CC} = 6.0$ V	-	9	19	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time n $\overline{OE}$ to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	36	150	ns
		$V_{CC} = 4.5$ V	-	13	30	ns
		$V_{CC} = 6.0$ V	-	10	26	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time n $\overline{OE}$ to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	39	150	ns
		$V_{CC} = 4.5$ V	-	14	30	ns
		$V_{CC} = 6.0$ V	-	11	26	ns
$t_{THL}$ , $t_{TLH}$	output transition time	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0$ V	-	14	60	ns
		$V_{CC} = 4.5$ V	-	5	12	ns
		$V_{CC} = 6.0$ V	-	4	10	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND$ to $V_{CC}$	[1]	-	35	pF
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0$ V	-	-	145	ns
		$V_{CC} = 4.5$ V	-	-	28	ns
		$V_{CC} = 6.0$ V	-	-	24	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time n $\overline{OE}$ to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	190	ns
		$V_{CC} = 4.5$ V	-	-	38	ns
		$V_{CC} = 6.0$ V	-	-	33	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time n $\overline{OE}$ to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	190	ns
		$V_{CC} = 4.5$ V	-	-	38	ns
		$V_{CC} = 6.0$ V	-	-	33	ns
$t_{THL}$ , $t_{TLH}$	output transition time	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0$ V	-	-	75	ns
		$V_{CC} = 4.5$ V	-	-	15	ns
		$V_{CC} = 6.0$ V	-	-	13	ns



**Table 9: Dynamic characteristics 74HC244 ...continued**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless otherwise specified; for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	165	ns
		$V_{CC} = 4.5\text{ V}$	-	-	33	ns
		$V_{CC} = 6.0\text{ V}$	-	-	28	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time nOE to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time nOE to nYn	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	-	45	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
$t_{THL}$ , $t_{TLH}$	output transition time	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	90	ns
		$V_{CC} = 4.5\text{ V}$	-	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	-	15	ns

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

**Table 10: Dynamic characteristics type 74HCT244**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless otherwise specified; for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ °C}</math></b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5\text{ V}$	-	13	22	ns
		$V_{CC} = 5\text{ V}$ ; $C_L = 15\text{ pF}$	-	11	-	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time nOE to nYn	$V_{CC} = 4.5\text{ V}$ ; see <a href="#">Figure 7</a>	-	15	30	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time nOE to nYn	$V_{CC} = 4.5\text{ V}$ ; see <a href="#">Figure 7</a>	-	15	25	ns
$t_{THL}$ , $t_{TLH}$	output transition time	$V_{CC} = 4.5\text{ V}$ ; see <a href="#">Figure 6</a>	-	5	12	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND$ to $(V_{CC} - 1.5\text{ V})$	[1]	35	-	pF

**Table 10: Dynamic characteristics type 74HCT244 ...continued**  
*GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 8.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	$V_{CC} = 4.5$ V; see Figure 6	-	-	28	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time nOE to nYn	$V_{CC} = 4.5$ V; see Figure 7	-	-	38	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time nOE to nYn	$V_{CC} = 4.5$ V; see Figure 7	-	-	31	ns
$t_{THL}$ , $t_{TLH}$	output transition time	$V_{CC} = 4.5$ V; see Figure 6	-	-	15	ns
<b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nAn to nYn	$V_{CC} = 4.5$ V; see Figure 6	-	-	33	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time nOE to nYn	$V_{CC} = 4.5$ V; see Figure 7	-	-	45	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time nOE to nYn	$V_{CC} = 4.5$ V; see Figure 7	-	-	38	ns
$t_{THL}$ , $t_{TLH}$	output transition time	$V_{CC} = 4.5$ V; see Figure 6	-	-	18	ns

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

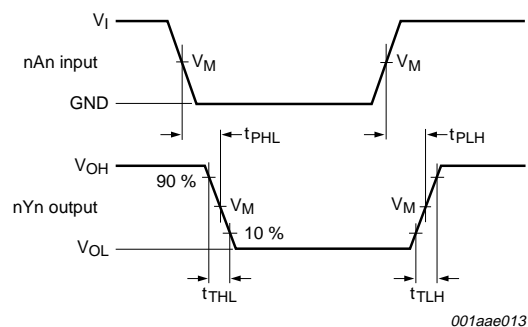
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 12. Waveforms



Measurement points are given in Table 11.

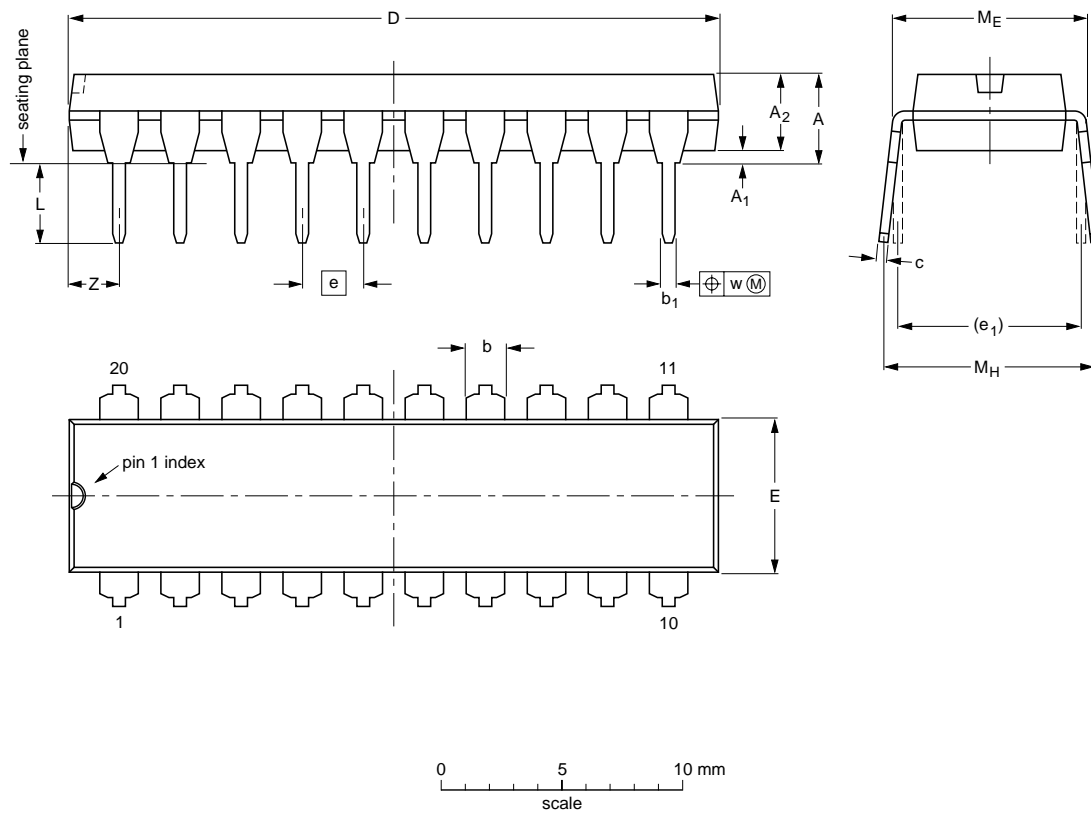
$V_{OL}$  and  $V_{OH}$  are typical voltage output drop that occur with the output load.

**Fig 6. Propagation delay input (1An, 2An) to output (1Yn, 2Yn) and transition time output (nYn)**

13. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION
	IEC	JEDEC	JEITA	
SOT146-1		MS-001	SC-603	

Fig 9. Package outline SOT146-1 (DIP20)